Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	653	bipolar adj transistor and base near2 (germanium ge)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:04
L2	431	L1 and @ad<"20020515"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:26
L3	146	L2 and emitter near3 polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:05
L4	5	L3 and emitter near8 carbon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:19
L5	97	bipolar adj transistor and (base adj current) near3 (current adj amplification adj factor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:25
L6	86	L5 and @ad<"20020515"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:27
L9	68	bipolar adj transistor and (base adj current) near3 (emitter adj resistance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:27
L10	56	L9 and @ad<"20020515"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:53

L11	0	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same "arsenic and antimony"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:52
L12	18	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same arsenic same antimony	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:56
L13	15	L12 and @ad<"20020515"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:56
L14	19	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same (arsenic and antimony)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:59
L15	15	L14 and @ad<"20020515"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:59
L16	0	L15 not L13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:57
L17	481	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same arsenic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 14:25
L18	217	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) near8 arsenic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:59

L19	190	L18 and @ad<"20020515"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:59
L20	26	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same antimony	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 14:25
L21	106	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same (antimony sb)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 14:26
L22	31	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) near8 (antimony sb)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 14:42
L23	26	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same (antimony)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 14:43
L24	20	L23 not L22	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 14:43
L25	17	L24 and @ad<"20020515"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 15:08
L26	1300	257/565.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 15:08

L27	256	257/565.ccor.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 15:12
L28	66	257/588.ccor.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 15:15
L29	40	257/591.ccor.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 15:16
L30	0	257/914.ccor.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 15:16
L31	118	257/914.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 15:17
L32	230	438/309.ccor.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 15:20
L33	65	438/369.ccor.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 15:22
L34	71	438/372.ccor.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 15:23

L35	121	438/488.ccor.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 15:23
L36	23	438/491.ccor.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 15:24
L37	19	438/532.ccor.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 15:24
S1	1	@pn="6682992"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/08 14:01
S2	3662	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/09 14:25
S3	861	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same (implant dopant)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/08 16:29
S4	481	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same arsenic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:52
S5	29	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same arsenic same (antimony sb carbon)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/08 16:42

S6	26	S5 and @ad<"20020515"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/08 14:09
S7	13	("4467519" | "4755476" | "5242844" | "5254484" | "5317432" | "5373192" | "5385863" | "5683935" | "5744824" | "5893747" | "6030874" | "6114722" | "6294442").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/09/08 16:17
S8	4	("4467519" | "4755476" | "5242844" | "5254484" | "5317432" | "5373192" | "5385863" | "5683935" | "5744824" | "5893747" | "6030874" | "6114722" | "6294442").PN. and emitter	US-PGPUB; USPAT; USOCR	OR	ON	2005/09/08 16:19
S9	1	@pn="4559696"	US-PGPUB; USPAT; USOCR	OR	ON	2005/09/08 16:28
S10	236	S2 and grain	US-PGPUB; USPAT; USOCR	OR	ON	2005/09/08 16:28
S11	59	S3 and grain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/08 16:29
S12	5	S5 and grain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/08 16:33
S13	359	257/64.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/08 16:33
S14	274	257/64.ccls. and @ad<"20020515"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/09 14:26

S15	29	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same arsenic same (antimony sb carbon)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/08 16:42
S16	71	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same grain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/08 16:42
S17	60	S16 and @ad<"20020515"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/09 14:25
S18	106	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same (antimony sb)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/09 14:25
S19	100	S18 and @ad<"20020515"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/09 16:34
S20	1	@pn="5360986"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/09 15:24
S21	13	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same grain and (base adj current)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 08:52
S22	1	NA9309253	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 08:50

S23	20	emitter near3 (polysilicon (polycrystalline adj silicon) polysi poly) same grain and (emitter adj resistance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 08:54
S24	35	polyemitter	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 08:54
S25	29	S24 and @ad<"20020515"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 08:54
S26	11	S25 and (arsenic as) and (carbon antimony sb)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 08:55
S27	12	S25 and (arsenic as) and (grain carbon antimony sb)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:20
S28	2	"20020145167"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 09:35
S29	5	polysilicon same carbon near3 dose	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 10:22
S30	8	polysilicon same carbon near3 energy	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/12 13:04